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AC Semiconductor Contactor pitch 22,5mm compact size and DIN rail mounting.

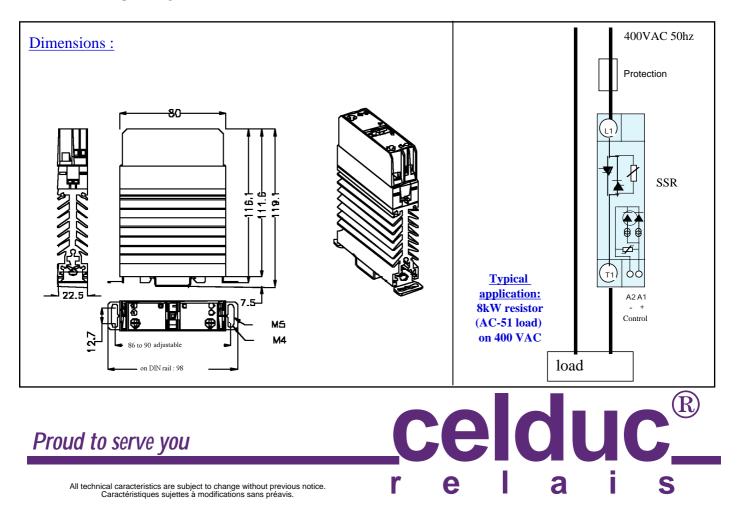
- □ Ready to use Single-Phase Relay: "Install it & Forget it!"
- Zero cross model : 24-510VAC 35A back to back thyristors on output -TMS² technology - I²t value > 1150A²s
- Large control range : 3,5-32VDC with an input current < 10 mA on all the range. Green LED visualization on the input.
- □ Very high immunity : Voltage protection on output and input- 4kV according IEC61000-4-4 & 5
- □ IP20 housing
- \Box Low leakage current (<1mA) and low zero cross voltage.
- □ Mounting and dismounting on DIN rail without any tool or directly mountable on panel.
- Designed in conformity with EN60947-4-3 (IEC947-4-3) and EN60950 -UL-cUL pending

SIL863170

Output : 24-510VAC 25A(*) Input : 3,5-32VDC / I<10mA



(*) see conditions (thermal curve page 3)

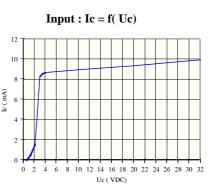


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Control characteristics (at $25^{\circ}C$)

		DC				
Paramètre / Parameter	Symbol	Min	Nom	Max	Unit	I
Control voltage	Uc	3,5	5-12-24	32	V	Ι
Control current (@ Uc)	Ic	<10	<10	<10	mA	
Release voltage	Uc off	2			V	
Input LED		green				
Reverse voltage	Urv	32			V	Ι
Clamping voltage	Uclamp	42		V		
Input immunity : EN61000-4-4		2kV				
Input immunity : EN61000-4-5		2KV				l



Output characteristics (at 20°C)

Operating rangeUemin-max24Peak voltageUp12Clamping voltageUclamp820 (iZero cross levelUsync12Latching voltageIe nomUaAC-51 nominal current : permanent(see Fig. 2 page 3)Ie AC-51AC-53 nominal currentIte nomIe AC-53Non repetitive overload currenttp=10ms (Fig. 3)ItsmOn state voltage drop (typical value)@ 25°CVt(implement)Output Power dissipation (typical value)Pd0,81xIe+Thermal resistance between junction to air@ Ue, 50HzIlkOutput Power dissipation (typical value)Wc nom DC, f=50HzIn maxTurn on timeUc nom DC, f=50Hzton maxTurn oft timeUc nom DC, f=50Hzf0,1Operating frequency rangeI ² / ₁ 1Conducted immunity levelIEC 1000-4-4 (burst)4kV crConducted immunity levelIEC 1000-4-5(schocks)4kV crConducted immunity levelIEC 1000-4-5(schocks)4kV crConducted immunity levelIEC 1000-4-4 (burst)4000Output to case insulationUi4000Insulation resistanceRi100 (@ 500VD)Rate displaceRi100 (@ 500VD)Rate displaceRi100 (@ 500VD)	00 V rms 510 V rms 00 V 91mA) V 0 V 9 V 5 A rms 30 A 9 V 5 m 0,015xIe ² W 2,7) K/W
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Rated impulse voltage Uimp 4000	VRMS
	V
Protection level / CEI529 - IP20	
Pollution degree - 2	
Vibration resistance 10 -55 Hz according to CEI68 : double amplitude 1,5 Shocks resistance according to CEI68 (on DIN rail / with screws) - 30/50	
Shocks resistance according to CEI68 (on DIN rail / with screws) - 30/50 Ambient temperature (with no icing or condensation) - -30/+80	mm
Ambient temperature (with no icing or condensation)30/+80Storage temperature (with no icing or condensation)-30/+100	g
Ambient humidity HR 40 to 85	g °C
Weight 260	g °C °C
Conformity EN60947-4-3 (IEC9	g °C °C %
Conformity EN60950 UL/cUL r	g °C °C % g





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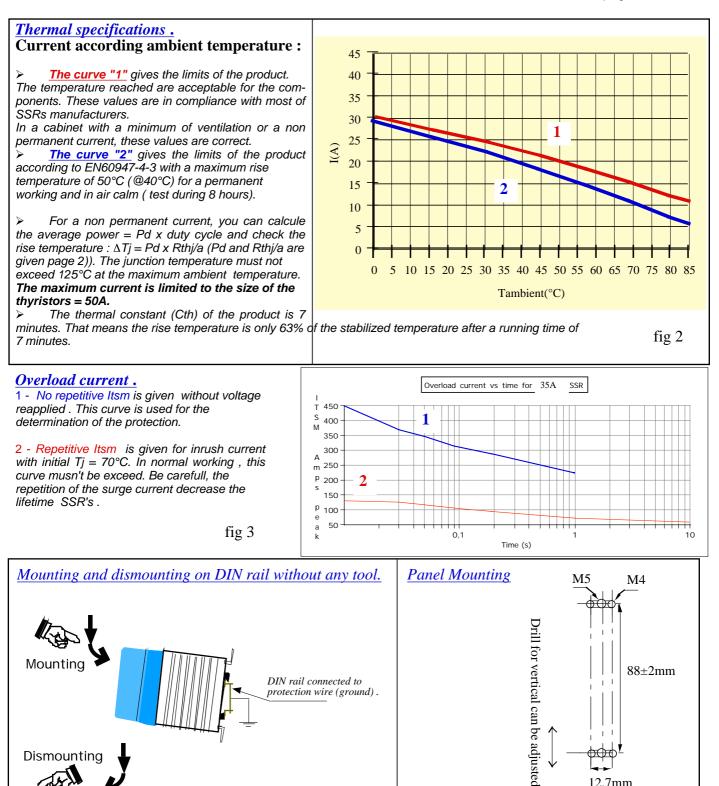
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Warning ! semiconductor relays don't provide any galvanic insulation between the load and the mains. Always use in conjunction with an adapted circuit breaker with isolation feature or a similar device in order to ensure a reliable isolation in the event of wrong function and when the relay must be insulated from the mains (maintenance; if not used for a long duration ...).





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12.7mm

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Connections .

> For the output terminals, the wire cross sections must be adapted to the load current and to the overcurrent protection device characteristics. The relay rated voltage must be adapted to the mains rated voltage.

> **celpac** use screw clamp connections.



wires	torques	screwdriver
(mm^2)		screwdriver
<u>control</u>		
1 x(0,75>2,5)	0,4N.m	3,5x0,5mm 😑
L = 6mm	(0,6N.m max)	
Power		
$1x(1,5>16) \mid 1 \mid x(1,5>10)$	1,2N.m	Pozidriv2/ 🔍
L = 10mm	(1,8N.m max)	0,8x5,5 (1x6)

Mounting

Warning: only in vertical position. The user should protect heat sensitive materials as well as persons against any contacts with the heatsink. For non vertical mounting, the load current must be 50% lower than the rated one. For a good cooling, the SSR needs an air convection. Less convection air produces an abnormal heating. Keep a distance between the upper SSR and the lower SSR. In case of no space between two SSR (zero space between two SSRs), please reduce the load current. For further details refer to below :

Derating current with no space between SSRs

AC-51 nominal currents are given with a space of 22,5mm between each SSR, for a permanent current during a minimum time of 8 hours in air calm according to IEC60947-4-3. In case of non permanent currents or in case of SSRs are mounted with no space, you must check the heatsink temperature never exceed 90°C. When the SSRs are mounted side to side (no space between each relay) a derating current of 25% must be take into account. A forced cooling (fan inside the cabinet) improves significantly the thermal performances.

Typical application : LOADS

SIL product is designed mainly for AC-51 résistive load. AC-53 motor current are also given . For other loads, check the inrush current at turn ON and possible overvoltages at turn OFF or consult us :

* AC-55b : Incandescent lamps : Inrush current is generally 10 times In during few 10ms. So limit the nominal current at about 15A.

* AC-55a : Electric discharge lamp : These loads often have overcurrent at turn ON and overvoltage at turn OFF, so we advise to use 400VAC SSR on 230VAC mains.

* AC-56a : Transformers loads : Very high inrush current up to 100 times In . We advise to use random SSR.

* AC-56b : Capacitors loads : Very high current at turn ON and overvolatge at turn OFF, please consult us with 1600V peak SSR with high inrush current.

Protection :

To protect the SSR against a short-circuit of the load , use a fuse with a l^2t value = $1/2 l^2t$ value specified page 2. A test has been made with FERRAZ fuse (see page 2).

It is possible to protect SSR by MCB (miniature circuit breaker). In this case, see application note (SSR protection) and use a SSR with high l^2t value (5000A²s minimum).

EMC :

Immunity :

We give in our data-sheets, the immunity level of our SSRs according to the main standards for this type of products : EN61000-4-4 &5. You can see the high immunity level in comparison with the products on the market.

Emission:

SSRs are complex devices which must be interconnected with other equipment (loads, cables, etc.) to form a system. Because the other equipment or the interconnections may not be under the control of **celduc**, it shall be the responsibility of the system integrator to ensure that systems containing SSRs comply with the requirements of any rules and regulations applicable at the system level. The very low zero cross voltage (<20V) improves the conducted emission level in comparison with most of SSR on the market with zero cross voltage higher than 50V. Consult **celduc** laboratory which can make some tests in your application.





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